Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-219-3653

| Inclosure Material: |
|---|
| Glass |
| Overall Length: |
| 0.200 inches |
| Terminal Length: |
| 1.500 inches |
| Overall Diameter: |
| 0.090 inches |
| Joint Electronic Device Engineering Council/jedec/case Outline Designation: |
| D0-35 |
| Mounting Method: |
| Terminal |
| Features Provided: |
| Hermetically sealed case |
| Semiconductor Material: |
| Silicon |
| Voltage Rating In Volts Per Characteristic: |
| 24.0 breakdown voltage, dc |
| Voltage Tolerance In Percent: |
| -5.0/+5.0 |
| Current Rating Per Characteristic: |
| 5.00 microamperes forward current, average peak |
| Power Rating Per Characteristic: |
| 400.0 milliwatts small-signal input power, common-collector preset |
| Terminal Type And Quantity: |
| 2 uninsulated wire lead |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| No |
| Fiig: |
| A110a0 |
| |
| |
| |